SILICON POWER TRANSISTOR 2SA1742

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1742 is a power transistor developed for high-speed switching and features a high hre at low $V_{CE(sat)}$. This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

NEC

- High hFE and low VCE(sat): hFE ≥ 100 MIN. @VCE = -2.0 V, IC = -1.5 A VCE(sat) ≥ -0.3 V MAX. @IC = -4.0 V, IB = -0.2 A
- Full-mold package that does not require an insulating board or bushing

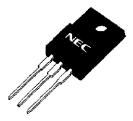
Parameter Symbol Conditions Ratings Unit -100 ٧ Collector to base voltage Vсво -60 v Collector to emitter voltage VCEO -7.0 V Emitter to base voltage Vево -7.0 Collector current (DC) IC(DC) А $\overline{PW} \le 300 \ \mu s$, Collector current (pulse) -14 А C(pulse) duty cycle $\leq 10\%$ -3.5 A Base current (DC) B(DC) Total power dissipation Pτ Tc = 25°C 30 W T_A = 25°C 2.0 W °C Junction temperature Tj 150 Storage temperature Tstg -55 to +150 °C

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

ORDERING INFORMATION

Part No.	Package
2SA1742	Isolated TO-220

(Isolated TO-220)



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ELECTRICAL CHARACTERISTICS (TA = 25°C)

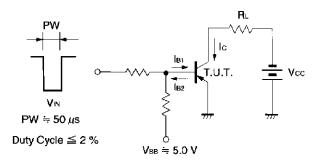
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = −4.0 V, I _B = −0.4 A, L = 1 mH	-60			V
	VCEX(SUS)	Ic = -4.0 A, I _{B1} = -I _{B2} = -0.4 A, V _{BE(OFF)} = 1.5 V, L = 180 μ H, clamped	-60			V
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0 \text{ A}$			-10	μA
	ICER	$V_{CE} = -60 \text{ V}, \text{ R}_{BE} = 50 \Omega, \text{ T}_{A} = 125^{\circ}\text{C}$			-1.0	mA
	ICEX1	$V_{\text{CE}} = -60 \text{ V}, \text{ V}_{\text{BE(OFF)}} = 1.5 \text{ V}$			-10	μA
	ICEX2	$\label{eq:Vce} \begin{split} V_{\text{CE}} &= -60 \ V, \ V_{\text{BE}(\text{OFF})} = 1.5 \ V, \\ T_{\text{A}} &= 125^{\circ}\text{C} \end{split}$			-1.0	mA
Emitter cutoff current	Іево	$V_{EB} = -5.0 \text{ V}, \text{ Ic} = 0 \text{ A}$			-10	μA
DC current gain	h _{FE1}	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.7 \text{ A}^{Note}$	100			
	hfe2	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.5 \text{ A}^{Note}$	100		400	
	hfe3	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -4.0 \text{ A}^{Note}$	60			
Collector saturation voltage	VCE(sat)1	$I_{C} = -4.0 \text{ A}, I_{B} = -0.2 \text{ A}^{Note}$			-0.3	V
	VCE(sat)2	$I_{C} = -6.0 \text{ A}, I_{B} = -0.3 \text{ A}^{Note}$			-0.5	V
Base saturation voltage	VBE(sat)1	$Ic = -4.0 A$, $I_B = -0.2 A^{Note}$			-1.2	V
	VBE(sat)2	$I_{C} = -6.0 \text{ A}, I_{B} = -0.3 \text{ A}^{Note}$			-1.5	V
Collector capacitance	Cob	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0 \text{ A}, \text{ f} = 1.0 \text{ MHz}$		180		pF
Gain bandwidth product	f⊤	Vcb = -10 V, lc = -1.0 A		40		MHz
Turn-on time	ton	lc = −4.0 A, RL = 12.5 Ω,			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.2 \text{ A}, \text{ Vcc} \cong -50 \text{ V}$			1.5	μs
Fall time	tr	Refer to the test circuit.			0.3	μs

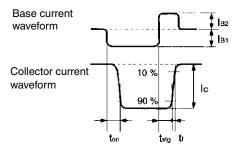
Note Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

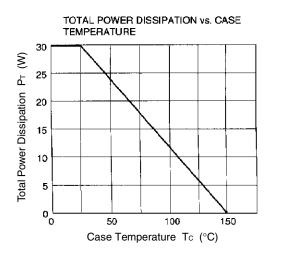
Marking	М	L	К
hfe2	100 to 200	150 to 300	200 to 400

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

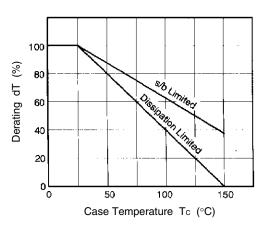




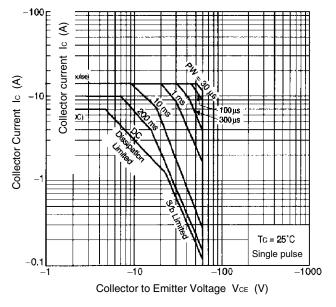




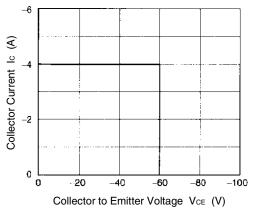
DERATING CURVE OF SAFE OPERATING AREA



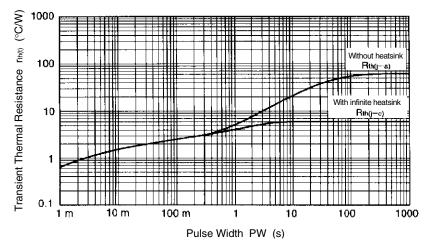
FORWARD BIAS SAFE OPERATING AREA

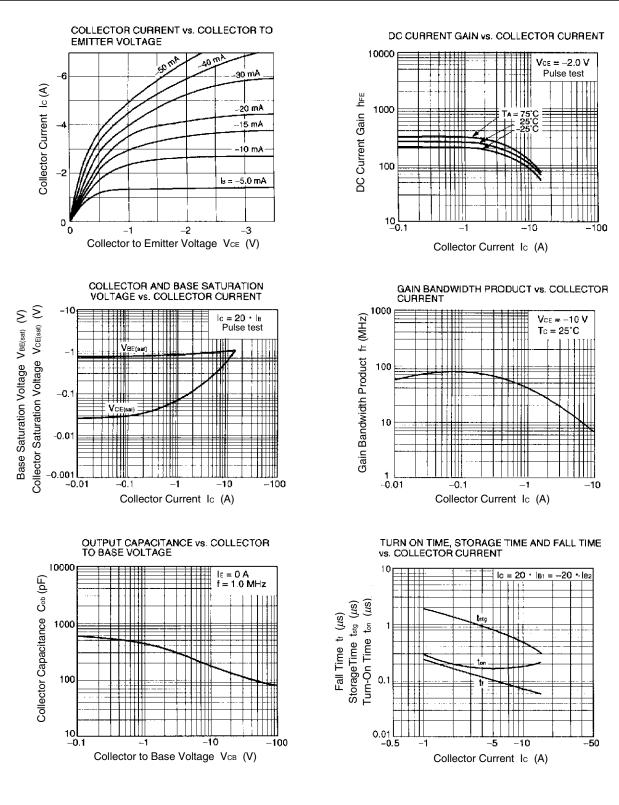


REVERSE BIAS SAFE OPERATING AREA



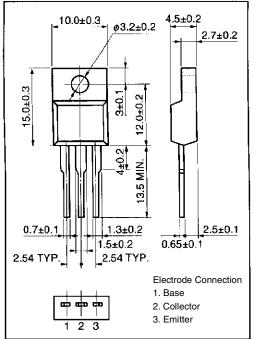
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH





PACKAGE DRAWING (UNIT: mm)





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